

Title (en)
OXIDE MEDIA FOR GETTERING IMPURITIES FROM SILICON WAFERS

Title (de)
OXIDMEDIEN ZUM GETTERN VON VERUNREINIGUNGEN AUS SILIZIUMWAFERN

Title (fr)
SUBSTANCES D'OXYDES DESTINÉES À EXTRAIRE PAR EFFET GETTER DES IMPURETÉS DE TRANCHES DE SILICIUM

Publication
EP 2938762 A1 20151104 (DE)

Application
EP 13821068 A 20131218

Priority

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Abstract (en)
[origin: WO2014101988A1] The invention relates to a novel method for producing printable, low- to high-viscous oxide media and to the use thereof in the production of solar cells.

IPC 8 full level
C09D 183/00 (2006.01); **C23C 18/12** (2006.01); **C23C 18/32** (2006.01); **C30B 31/04** (2006.01); **H01L 21/02** (2006.01); **H01L 21/22** (2006.01); **H01L 21/225** (2006.01); **H01L 21/48** (2006.01); **H01L 31/0216** (2014.01); **H01L 31/0288** (2006.01); **H01L 31/18** (2006.01)

CPC (source: EP US)
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Citation (search report)
See references of WO 2014101988A1

Designated contracting state (EPC)
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BA ME

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WO 2014101988 A1 20140703; CN 104884684 A 20150902; EP 2938762 A1 20151104; JP 2016506629 A 20160303; KR 20150103129 A 20150909; SG 10201705329R A 20170728; SG 11201505028X A 20150730; TW 201443108 A 20141116; US 2015357508 A1 20151210

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